

Alloy phase diagram of InGaN/GaN(0001) pseudomorphic thin film and strain-induced superlattice structure: Monte Carlo simulation study

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InGaN materials have been expected to cover the entire visible light region. $\text{In}_x\text{Ga}_{1-x}\text{N}$ materials with large x were, however, achieved very recently. We have conjectured that the difficulty is due to miscibility gap at the large x region. To elucidate, we performed semi-grand canonical ($N\Delta\mu PT$ -constant) Monte Carlo (MC) simulation [1]; where $\Delta\mu \equiv \mu_{\text{InN}} - \mu_{\text{GaN}}$ with InGaN being stoichiometric. Though the alloy phase diagram was incomplete yet, it supports the conjecture [2,3]. The multi valley free energy landscape, which caused the difficulty, was found to originate in the strain-induced superlattice ordering due to the substrate [3,4]. The final goal is construction of the alloy phase diagram with sub-branches of difference superlattice ordering being distinguished.

Due to discontinuity the thermodynamic integrals to calculate the free energy difference were just approximately done [2,3]. We circumvent relying on the acceptance ratio method [5]. We obtain the free energy difference between phases i ($i = 1, 2$) as the difference between C 's at two intersecting points between

$$Y^{(i)}(C) = \left\langle \left[1 + \exp(\beta U^{\text{ref}} - \beta U + C) \right]^{-1} \right\rangle_U^{(i)} \quad \text{and} \quad Y_{\text{ref}}(C) = \left\langle \left[1 + \exp(\beta U - \beta U^{\text{ref}} - C) \right]^{-1} \right\rangle_{U^{\text{ref}}},$$

where $\beta = (k_B T)^{-1}$, the subscript under the brackets denotes the interaction potential in MC simulation, the superscript (i) indicates that the sampling is made for phase (i) . We note that PV and $N_{\text{In}}\Delta\mu$ contributions cancel if, respectively, βP and $\beta\Delta\mu$ are identical for the system under investigation and the reference. An empirical interatomic potential is used for the system potential U , and a harmonic potential as the reference potential U^{ref} . We have successfully calculated the free energy difference between sub-branches.

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